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Power Matters.

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Overview	Docs &	Diagrams				
Electrical Rating	Symbol	Min	Тур	Max		Unit
DC Current Gain	HFE	20.00		200.00		
Maximum Electrical Rating		Symbol	Min	Тур	Max	Unit
Collector Current (dc)		I _C			0.05	А
Collector-Emitter Voltage (Base Open)		V _{CEO}			15.00	V
Junction Temperature (°C)		T _J			200.00	°C

This part can be found in the following product categories:

- ▶ Non-Radiation Hardened Devices ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ NPN Transistor
- → Discretes → Transistors → BJT(BiPolar Junction Transistor) → NPN Transistor

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